Small Signal MOSFET

60 V, 340 mA, Single, N-Channel, SC-70

Features

- ESD Protected
- Low R_{DS(on)}
- Small Footprint Surface Mount Package
- 2V Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- Low Side Load Switch
- Level Shift Circuits
- DC–DC Converter
- Portable Applications i.e. DSC, PDA, Cell Phone, etc.

MAXIMUM RATINGS (T_J = 25° C unless otherwise stated)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V _{DSS}	60	V
Gate-to-Source Voltage	V _{GS}	±20	V
$\label{eq:target} \begin{array}{ c c c } \hline \text{Drain Current (Note 1)} & & & \\ & & \text{Steady State} & & T_A = 25^\circ\text{C} \\ & & T_A = 85^\circ\text{C} \\ & & & T_A = 25^\circ\text{C} \\ & & & T_A = 85^\circ\text{C} \end{array}$	ID	310 220 340 240	mA
Power Dissipation (Note 1) Steady State t < 5 s	P _D	280 330	mW
Pulsed Drain Current ($t_p = 10 \ \mu s$)	I _{DM}	1.4	А
Operating Junction and Storage Temperature Range	T _J , T _{STG}	–55 to +150	°C
Source Current (Body Diode)	۱ _S	250	mA
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)	TL	260	°C
Gate–Source ESD Rating (HBM, Method 3015)	ESD	2000	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Junction-to-Ambient - Steady State (Note 1)	R_{\thetaJA}	450	°C/W
Junction-to-Ambient - t \leq 5 s (Note 1)	R_{\thetaJA}	375	

1. Surface-mounted on FR4 board using 1 in sq pad size (Cu area = 1.127 in sq [1 oz] including traces)

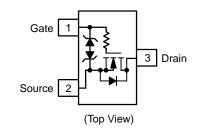


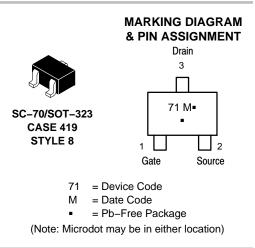
ON Semiconductor®

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V _{(BR)DSS}	R _{DS(on)} MAX	I _D MAX (Note 1)	
60.1/	1.6 Ω @ 10 V	340 mA	
60 V	2.5 Ω @ 4.5 V	340 MA	

SIMPLIFIED SCHEMATIC





ORDERING INFORMATION

Device	Package	Shipping [†]
2N7002WT1G	SC-70 (Pb-Free)	3000/Tape & Reel
2V7002WT1G	SC–70 (Pb–Free)	3000/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise specified)

Parameter	Symbol	Test C	ondition	Min	Тур	Max	Units
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I_D = 250 μ A		60			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /T _J				71		mV/°C
Zero Gate Voltage Drain Current	I _{DSS} Va	V _{GS} = 0 V,	$T_J = 25^{\circ}C$			1.0	μΑ
		$V_{DS} = 60 V$	T _J = 150°C			15	μA
		V _{GS} = 0 V,	$T_J = 25^{\circ}C$			100	nA
		$V_{DS} = 50 V$	T _J = 150°C			10	μA
Gate-to-Source Leakage Current	I _{GSS}	$I_{GSS} \qquad V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$ $V_{DS} = 0 \text{V}, V_{GS} = \pm 10 \text{V}$				±10	μA
						450	nA
		V _{DS} = 0 V,	V _{GS} = ±5.0 V			150	nA
ON CHARACTERISTICS (Note 2)							
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_D = 250 \ \mu A$		1.0		2.5	V
Negative Threshold Temperature Coefficient	V _{GS(TH)} /T _J				4.0		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V_{GS} = 10 V, I _D = 500 mA V_{GS} = 4.5 V, I _D = 200 mA			1.19	1.6	Ω
					1.33	2.5	
Forward Transconductance	9 _{FS}	$V_{DS} = 5 \text{ V}, \text{ I}_{D} = 200 \text{ mA}$			530		mS
CHARGES AND CAPACITANCES							
Input Capacitance	C _{ISS}				24.5		pF
Output Capacitance	C _{OSS}		/, f = 1 MHz, = 20 V		4.2		7
Reverse Transfer Capacitance	C _{RSS}	VDS	- 20 V		2.2		
Total Gate Charge	Q _{G(TOT)}				0.7		nC
Threshold Gate Charge	Q _{G(TH)}	V _{GS} = 4.5 \	/, V _{DS} = 10 V;		0.1		
Gate-to-Source Charge	Q _{GS}	$I_D = 2$	/, V _{DS} = 10 V; 200 mA		0.3		
Gate-to-Drain Charge	Q _{GD}	1			0.1		1
SWITCHING CHARACTERISTICS, V _{GS}	= V (Note 3)						
Turn-On Delay Time	t _{d(ON)}	V_{GS} = 10 V, V _{DD} = 25 V, I _D = 500 mA, R _G = 25 Ω			12.2		ns
Rise Time	t _r				9.0		1
Turn-Off Delay Time	t _{d(OFF)}				55.8		1
Fall Time	t _f				29		1

DRAIN-SOURCE DIODE CHARACTERISTICS

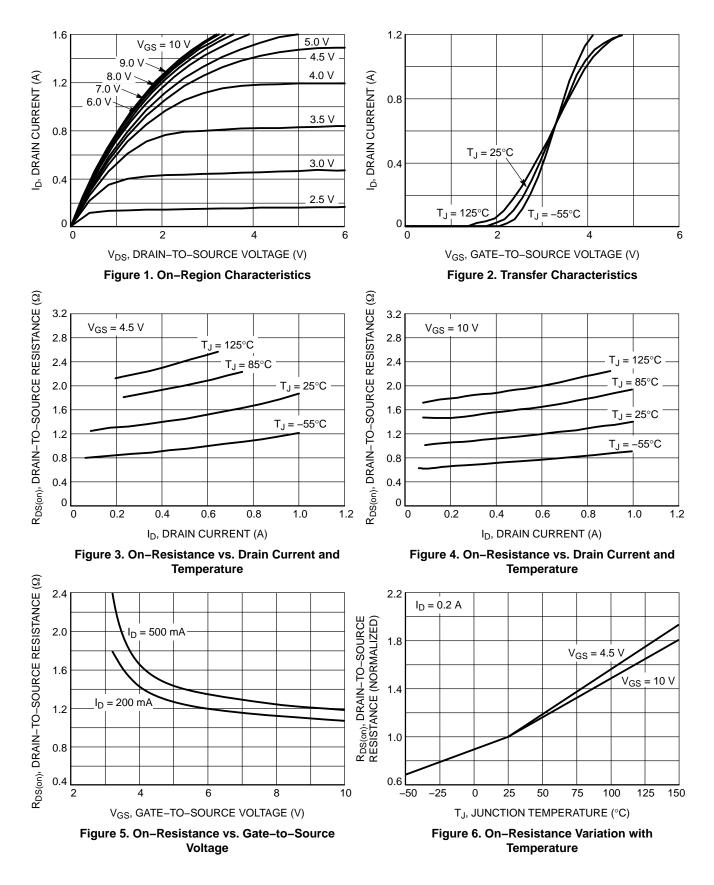
Forward Diode Voltage	V _{SD}	V _{GS} = 0 V,	$T_J = 25^{\circ}C$	0.8	1.2	V
		I _S = 200 mA	$T_J = 85^{\circ}C$	0.7		

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

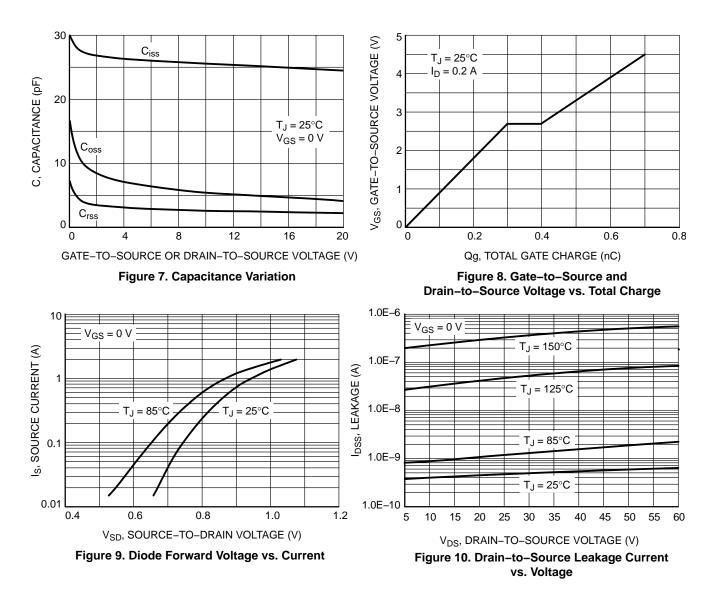
2. Pulse Test: pulse width \leq 300 µs, duty cycle \leq 2%

3. Switching characteristics are independent of operating junction temperatures

TYPICAL CHARACTERISTICS

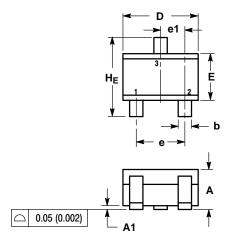


TYPICAL CHARACTERISTICS



PACKAGE DIMENSIONS

SC-70 (SOT-323) CASE 419-04 **ISSUE N**



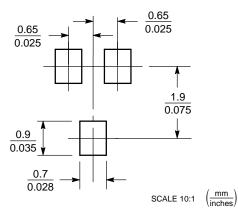
NOTES:

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.80	0.90	1.00	0.032	0.035	0.040	
A1	0.00	0.05	0.10	0.000	0.002	0.004	
A2	0.70 REF			0.028 REF			
b	0.30	0.35	0.40	0.012	0.014	0.016	
С	0.10	0.18	0.25	0.004	0.007	0.010	
D	1.80	2.10	2.20	0.071	0.083	0.087	
Е	1.15	1.24	1.35	0.045	0.049	0.053	
е	1.20	1.30	1.40	0.047	0.051	0.055	
e1	0.65 BSC			0.026 BSC			
L	0.20	0.38	0.56	0.008	0.015	0.022	
HE	2 00	2 10	2 40	0.079	0.083	0.095	



SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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